Integrated Current Transducer GO-SME series

Definition

The GO-SME series is a LEM integrated current transducer solution designed to measure AC and DC currents in both industrial and automotive applications. The differential sensing technique allows the transducer to reject an external field coming from a noisy environment. Proprietary stress and temperature compensation algorithms are implemented in order to achieve very good accuracy over wide temperature range. The primary conductor (pins 1 to 4) has a very low electrical resistance of 0.9 mΩ (typical), which enables excellent performance and low power losses. The GO-SME is capable of measuring continuous currents from 20 to 50 A over wide temperature range. The galvanic insulation between the primary and the secondary eliminates the need for any additional insulation, reducing the total footprint and cost of the system.

Main features & advantages

- Open loop multi-range current transducer: 50 A
- Low electrical resistance 0.9 mΩ
- Dual supply voltage 5 V or 3.3 V
- High bandwidth: 300 kHz
- No magnetic hysteresis
- 1 % total error over temperature
- Galvanic separation between primary and secondary with 4 mm of d_{Cl} and d_{Cp}
- Insulated test voltage 2400 V RMS
- AEC-Q-100 Grade 1.

Typical applications

- Small drives
- HVAC inverters
- Appliances
- Solar inverters
- E-Bikes
- Automotive & Industry qualified.

Standards

- IEC 61800-5-1: 2007
- IEC 62109-1: 2010
- IEC 62368-1:2018 (supersedes IEC 60950-1: 2005)
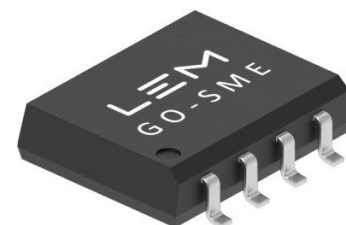- UL 1577: 2014
- UL 62368: 2019.

Figure 1: GO-SME package - SOIC-8
(Not to scale - For illustration: not representative)
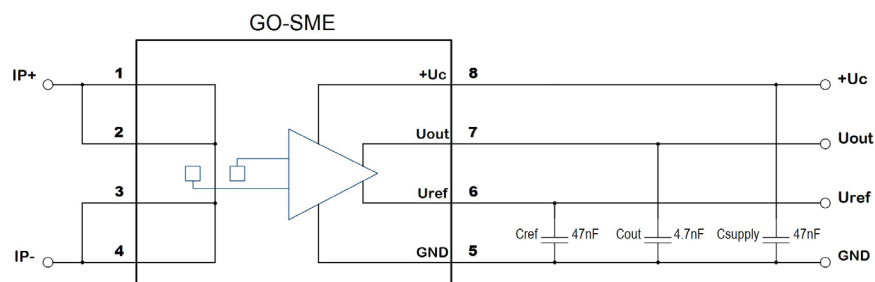
Application circuit and pinout

Figure 2: Application circuit

Table 1

Pin#	Name	Type	Function
1	I_{P+}	IN/OUT	Positive input of the primary current
2	I_{P+}	IN/OUT	Positive input of the primary current
3	I_{P-}	IN/OUT	Negative input of the primary current
4	I_{P-}	IN/OUT	Negative input of the primary current
5	GND	PWR	Ground terminal
6	U_{ref}	IN/OUT	Reference voltage
7	U_{out}	OUT	Output voltage
8	$+U_C$	PWR	Supply voltage

Table 2

External circuit example#	Min	Typ	Max	Unit
$C_{L\,out}$		4.7	6	nF
$C_{L\,supply}$		47		nF
$C_{L\,ref}$		47	100	nF

Note: For ratiometric versions of the product, C_{ref} is not necessary.

Available products

Product name#	Current measurement range (A max)	Nominal current (A RMS) [1)	Supply voltage U_C	Ratiometricity	Temperature range (°C)
GO 10-SME	±25	±10	5 V	N	
GO 20-SME	±50	±20	5 V	N	
GO 12-SME/SP2	±30	±12	5 V	Y	
GO 20-SME/SP2	±50	±20	5 V	Y	−40 ... 125 °C
GO 10-SME/SP3	±25	±10	3.3 V	N	
GO 20-SME/SP3	±50	±20	3.3 V	N	
GO 8-SME/SP4	±20	±8	3.3 V	Y	
GO 15-SME/SP4	±37.5	±15	3.3 V	Y	

Other configurations available, contact LEM for more options.

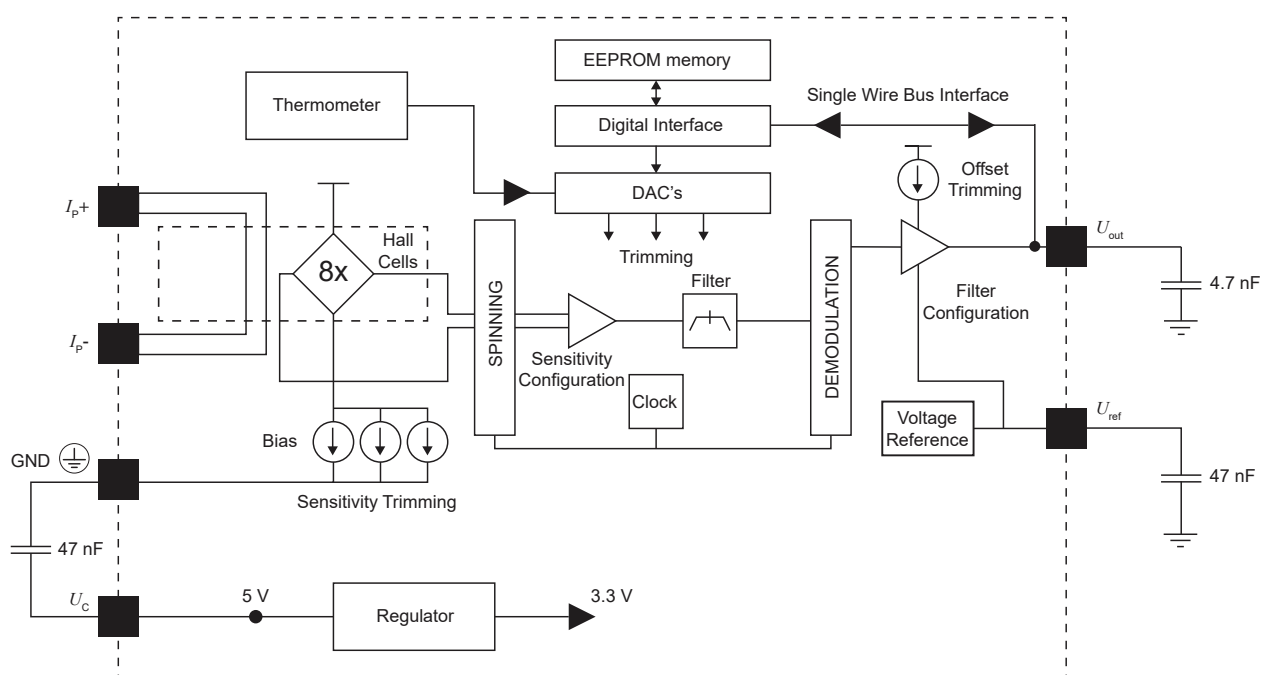Note: [1)] Trimmings at LEM are done at this nominal current.

Block diagram

Figure 3: Block diagram GO-SME

LEM reserves the right to carry out modifications on its transducers, in order to improve them.

Absolute maximum ratings

Parameter	Symbol	Unit	Min	Max	Conditions
Ambient operating temperature	T_A	°C	−40	125	
Ambient storage temperature	$T_{A\,st}$	°C	−40	150	
Maximum junction temperature	$T_{J\,max}$	°C		165	
Output sink current		mA		50	
Output source current		mA		25	

Absolute maximum ratings apply at 25 °C unless otherwise noted.
Stresses above these ratings may cause permanent damage.
Exposure to absolute maximum ratings for extented periods may degrade reliability.

Environmental and mechanical characteristics

Parameter	Symbol	Unit	Value
Maximum supply voltage (not destructive)	$U_{C\,max}$	V	8
Maximum supply voltage on other pins (not entering non-standard modes)			6.5
Electrostatic discharge voltage (HMB-Human Body Model)	$U_{ESD\,HBM}$	kV	2
Electrostatic discharge voltage (CDM-Charged Device Model)	$U_{ESD\,CDM}$	V	500
Thermal resistance junction to board [1]	$R_{th\,JB}$	K/W	15
Time constant (to reach steady state)	t	s	1
Mass	m	g	0.07

Note: [1] Done with LEM evaluation board PCB 2320-03 described on later paragraph.

Parameter	Symbol	Unit	Value	Comment
RMS voltage for AC insulation test, 50 Hz, 1 min	U_d	kV	2.5 [1]	According to IEC 62368
RMS voltage for AC insulation test, 60 Hz, 1 min	U_d	kV	2.5	According to UL 62368 & UL 1577
RMS voltage for AC insulation test, 50 Hz, 1 min	U_d	kV	2.5	According to IEC 60664-1
Impulse withstand voltage 1.2/50 μs	U_{Ni}	kV	4	According to IEC 62109-1, IEC 61800-5-1
Partial discharge recurring peak voltage	U_{PD}	V	330	According to IEC 62109-1, IEC 61800-5-1
Partial discharge test inception RMS voltage [2]	U_i	V	619	According to IEC 62109-1, IEC 61800-5-1
Partial discharge extinction RMS test voltage		V	495	According to IEC 62109-1, IEC 61800-5-1
Clearance (pri. - sec.)	d_{Cl}	mm	4	Shortest distance through air
Creepage distance (pri. - sec.)	d_{Cp}			Shortest path along body
Comparative tracking index	CTI		600	Grade requirements mass compound

Notes: [1] Tested at 2.5 kV in production
[2] $U_i = U_{PD} \cdot 1.875$.

Working voltage according to IEC 62368-1

Working voltages		PD 2	Standards
Basic insulation	RMS voltage	> 600 V	According to IEC 62368-1 (replacing IEC 60950-1)
	Peak or DC voltage	847 V	
Reinforced insulation	RMS voltage	300 V	
	Peak or DC voltage	423 V	

Rated insulation voltage according to IEC 61800-5-1 / IEC 62109-1

Rated insulation voltage		OV II / PD 2	OV III / PD 2	Standards
Basic insulation	RMS voltage	600 / 600	300 / 300	According to IEC 61800-5-1 and IEC 62109-1
	Peak or DC voltage	NA/ 848	NA/ 424	
Reinforced insulation	RMS voltage	300 / 300	150 / 150	
	Peak or DC voltage	NA/ 424	NA/ 212	

UL 62368-1 Audio/Video, information and communication technology equipment - Component

File # E521147, Vol 1
Audio/Video, Information and Communication Technology Equipment - component, 4800 V AC Insulation

Standard

● UL 62368-1, Audio/video, information and communication technology equipment.

Marking

Only those products bearing the UL or UR Mark should be considered to be Listed or Recognized and covered under UL's Follow-Up Service. Always look for the Mark on the product.

UL 1577 Non Optical insulating devices - Component

File # E486776, Vol 1
Single protection, non-optical isolators, 2500 V AC insulation

Standards

- UL 1577, Optical Isolators;
- CSA Component Acceptance Service Notice N°. 5 A, Component Acceptance Service for Optocouplers and Related Devices.

Marking

Only those products bearing the UL or UR Mark should be considered to be Listed or Recognized and covered under UL's Follow-Up Service. Always look for the Mark on the product.

LEM reserves the right to carry out modifications on its transducers,
in order to improve them.

Common electrical data (independent of sensitivity)

At T_A = 25 °C, U_C = +5 V or +3.3 V, R_L = 100 kΩ unless otherwise noted
(see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
DC supply voltage	U_C	V	4.5	5	5.5	Standard & SP2 versions
DC supply voltage			3.14	3.3	3.47	SP3 & SP4 versions
Output voltage range @ I_{PM}	$U_{out} - U_{ref}$	V	−2		2	U_C = 5 V
			−1.25		1.25	U_C = 3.3 V
Output internal resistance of U_{out}	R_{out}	Ω		1	5	Up to 10 kHz
Primary resistance @ T_A = 25 °C	R_P	mΩ		0.9		
Internal series resistance of reference voltage source	R_{ref}	Ω	120	200	333	
Maximum output current source of U_{out}		mA	25			Up to 10 kHz
Maximum input current sink of U_{out}		mA	20			Up to 10 kHz
Output leakage current		µA		2	20	
Maximum output current source of U_{ref}		mA		0.5		
Maximum input current sink of U_{ref}		mA		0.5		
Load capacitance on U_{out}	C_L	nF	0	4.7	6	
Load capacitance on U_{ref}			0	47	100	
DC current consumption	I_C	mA		20	26	U_C = 5 V
				20	26	U_C = 3.3 V
Electrical offset voltage	U_{OE}	mV	−5		5	$U_{out} - U_{ref}$ @ U_{ref} = 2.5 V
Temperature coefficient of U_{ref}	TCU_{ref}	ppm/K	−170		170	−40 ° C... +125 °C
Temperature coefficient of U_{OE}	TCU_{OE}	mV/K	−0.075		0.075	−40 ° C... +125 °C
Delay time to 10 % of the final output value for I_{PN} step	t_{D10}	µs			1.5	
Delay time to 90 % of the final output value for I_{PN} step	t_{D90}	µs			2	
Frequency bandwidth −3 dB, T_A = 25 °C	BW	kHz		300		

At T_A = 25 °C, U_C = +5 V, R_L = 100 kΩ unless otherwise noted. Output mode: referred to internal or external reference (see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
Primary nominal RMS current	I_{PN}	A		10		800 mV on U_{out}
Primary current, measuring range	I_{PM}	A	−25		25	Full scale: 2 V on U_{out}
Internal reference voltage @ I_{PN} = 0	$U_{I\,ref}$	V	2.48	2.5	2.52	
Nominal sensitivity	S_N	mV/A		80		800 mV @ I_{PN}
Temperature coefficient of S	TCS	ppm/K	−150		150	−40 °C ... 125 °C
Electrical offset current referred to I_{PN}	I_{OE}	mA	−62.5		62.5	
Temperature coefficient of I_{OE}	TCI_{OE}	mA/K	−0.94		0.94	−40 °C ... 125 °C
Lifetime offset drift		mV		±2		
Noise voltage spectral density	u_{no}	$\frac{\mu V}{\sqrt{Hz}}$		14.5		100 Hz ... 100 kHz
Sensitivity error	ε_S	%	−1		1	
Lifetime sensitivity error		% S		±1	±2	
Linearity error 0 ... I_{PN}	ε_L	% of I_{PN}	−0.3		0.3	Referred to I_{PN}
Linearity error 0 ... I_{PM}	ε_L	% of I_{PM}	−0.6		0.6	Referred to I_{PM}
Sum of sensitivity and linearity @ I_{PN}, @ T_A = 25 °C	ε_{SL25}	% of I_{PM}	−0.7		0.7	
Total error over temperature	ε_{tot}	% of I_{PM}	−1		1	

Electrical data GO 20-SME

At T_A = 25 °C, U_C = +5 V, R_L = 100 kΩ unless otherwise noted. Output mode: referred to internal or external reference. (see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
Primary nominal RMS current	I_{PN}	A		20		800 mV on U_{out}
Primary current, measuring range	I_{PM}	A	−50		50	Full scale: 2 V on U_{out}
Internal reference voltage @ I_{PN} = 0	$U_{I\,ref}$	V	2.48	2.5	2.52	
Nominal sensitivity	S_N	mV/A		40		800 mV @ I_{PN}
Temperature coefficient of S	TCS	ppm/K	−150		150	−40 °C ... 125 °C
Electrical offset current referred to I_{PN}	I_{OE}	mA	−125		125	
Temperature coefficient of I_{OE}	TCI_{OE}	mA/K	−1.88		1.88	−40 °C ... 125 °C
Lifetime offset drift		mV		±2		
Noise voltage spectral density	u_{no}	$\frac{\mu V}{\sqrt{Hz}}$		7		100 Hz ... 100 kHz
Sensitivity error	ε_S	%	−1		1	
Lifetime sensitivity error		% S		±2		
Linearity error 0 ... I_{PN}	ε_L	% of I_{PN}	−0.3		0.3	Referred to I_{PN}
Linearity error 0 ... I_{PM}	ε_L	% of I_{PM}	−0.6		0.6	Referred to I_{PM}
Sum of sensitivity and linearity @ I_{PN}, @ T_A = 25 °C	ε_{SL25}	% of I_{PM}	−0.7		0.7	
Total error over temperature	ε_{tot}	% of I_{PM}	−1		1	

Electrical data GO 12-SME/SP2

At T_A = 25 °C, U_C = +5 V, R_L = 100 kΩ unless otherwise noted. Output mode: ratiometric.
(see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
Primary nominal RMS current	I_{PN}	A		12.12		800 mV on U_{out}
Primary current, measuring range	I_{PM}	A	−30.3		30.3	Full scale: 2 V on U_{out}
Internal reference voltage @ I_{PN} = 0	$U_{I\,ref}$	V	2.48	2.5	2.52	
Nominal sensitivity	S_N	mV/A		66		800 mV @ I_{PN}
Temperature coefficient of S	TCS	ppm/K	−150		150	−40 °C ... 125 °C
Electrical offset current referred to I_{PN}	I_{OE}	mA	−75.7		75.7	
Temperature coefficient of I_{OE}	TCI_{OE}	mA/K	−1.14		1.14	−40 °C ... 125 °C
Lifetime offset drift		mV		±2		
Noise voltage spectral density	u_{no}	$\frac{\mu V}{\sqrt{Hz}}$		12.5		100 Hz ... 100 kHz
Sensitivity error	ε_S	%	−1		1	
Lifetime sensitivity error		% S		±1	±2	
Linearity error 0 ... I_{PN}	ε_L	% of I_{PN}	−0.3		0.3	Referred to I_{PN}
Linearity error 0 ... I_{PM}	ε_L	% of I_{PM}	−0.6		0.6	Referred to I_{PM}
Sum of sensitivity and linearity @ I_{PN}, @ T_A = 25 °C	ε_{SL25}	% of I_{PM}	−0.7		0.7	
Total error over temperature	ε_{tot}	% of I_{PM}	−1		1	

Electrical data GO 20-SME/SP2

At T_A = 25 °C, U_C = +5 V, R_L = 100 kΩ unless otherwise noted
(see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
Primary nominal RMS current	I_{PN}	A		20		
Primary current, measuring range	I_{PM}	A	−50		50	
Internal reference voltage @ I_{PN} = 0	$U_{I\,ref}$	V	2.48	2.5	2.52	
Nominal sensitivity	S_N	mV/A		40		800 mV @ I_{PN}
Temperature coefficient of S	TCS	ppm/K	−150		150	−40 °C ... 125 °C
Electrical offset current referred to I_{PN}	I_{OE}	mA	−125		125	
Temperature coefficient of I_{OE}	TCI_{OE}	mA/K	−1.88		1.88	−40 °C ... 125 °C
Lifetime offset drift		mV		±2		
Noise voltage spectral density	u_{no}	$\frac{\mu V}{\sqrt{Hz}}$		7		100 Hz ... 100 kHz
Sensitivity error	ε_S	%	−1		1	
Lifetime sensitivity error		% S		±1	±2	
Linearity error 0 ... I_{PN}	ε_L	% of I_{PN}	−0.3		0.3	Referred to I_{PN}
Linearity error 0 ... I_{PM}	ε_L	% of I_{PM}	−0.6		0.6	Referred to I_{PM}
Sum of sensitivity and linearity @ I_{PN}, @ T_A = 25 °C	ε_{SL25}	% of I_{PM}	−0.7		0.7	
Total error over temperature	ε_{tot}	% of I_{PM}	−1		1	

At T_A = 25 °C, U_C = +3.3 V, R_L = 100 kΩ unless otherwise noted. Output mode: referred to internal or external reference.
(see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
Primary nominal RMS current	I_{PN}	A		10		800 mV on U_{out}
Primary current, measuring range	I_{PM}	A	−25		25	Full scale: 2 V on U_{out}
Internal reference voltage @ I_{PN} = 0	$U_{I\,ref}$	V	1.63	1.65	1.67	
Nominal sensitivity	S_N	mV/A		50		500 mV @ I_{PN}
Temperature coefficient of S	TCS	ppm/K	−150		150	−40 °C ... 125 °C
Electrical offset current referred to I_{PN}	I_{OE}	mA	−100		100	
Temperature coefficient of I_{OE}	TCI_{OE}	mA/K	−1.5		1.5	−40 °C ... 125 °C
Lifetime offset drift		mV		±2		
Noise voltage spectral density	u_{no}	$\frac{\mu V}{\sqrt{Hz}}$		8		100 Hz ... 100 kHz
Sensitivity error	ε_S	%	−1		1	
Lifetime sensitivity error		% S		±1	±2	
Linearity error 0 ... I_{PN}	ε_L	% of I_{PN}	−0.3		0.3	Referred to I_{PN}
Linearity error 0 ... I_{PM}	ε_L	% of I_{PM}	−0.6		0.6	Referred to I_{PM}
Sum of sensitivity and linearity @ I_{PN}, @ T_A= 25 °C	$\varepsilon_{S\,L\,25}$	% of I_{PM}	−0.7		0.7	
Total error over temperature	ε_{tot}	% of I_{PM}	−1		1	

Electrical data GO 20-SME/SP3

At T_A = 25 °C, U_C = +3.3 V, R_L = 100 kΩ unless otherwise noted. Output mode: referred to internal or external reference.
(see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
Primary nominal RMS current	I_{PN}	A		20		800 mV on U_{out}
Primary current, measuring range	I_{PM}	A	−50		50	Full scale: 2 V on U_{out}
Internal reference voltage @ I_{PN} = 0	$U_{I\,ref}$	V	1.63	1.65	1.67	
Nominal sensitivity	S_N	mV/A		25		500 mV @ I_{PN}
Temperature coefficient of S	TCS	ppm/K	−150		150	−40 °C ... 125 °C
Electrical offset current referred to I_{PN}	I_{OE}	mA	−200		200	
Temperature coefficient of I_{OE}	TCI_{OE}	mA/K	−3		3	−40 °C ... 125 °C
Lifetime offset drift		mV		±2		
Noise voltage spectral density	u_{no}	$\frac{\mu V}{\sqrt{Hz}}$		4.5		100 Hz ... 100 kHz
Sensitivity error	ε_S	%	−1		1	
Lifetime sensitivity error		% S		±1	±2	
Linearity error 0 ... I_{PN}	ε_L	% of I_{PN}	−0.3		0.3	Referred to I_{PN}
Linearity error 0 ... I_{PM}	ε_L	% of I_{PM}	−0.6		0.6	Referred to I_{PM}
Sum of sensitivity and linearity @ I_{PN}, @ T_A= 25 °C	$\varepsilon_{S\,L\,25}$	% of I_{PM}	−0.7		0.7	
Total error over temperature	ε_{tot}	% of I_{PM}	−1		1	

Electrical data GO 8-SME/SP4

At T_A = 25 °C, U_C = +3.3 V, R_L = 100 kΩ unless otherwise noted. Output mode: ratiometric.
(see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
Primary nominal RMS current	I_{PN}	A		8		800 mV on U_{out}
Primary current, measuring range	I_{PM}	A	−20		20	Full scale: 2 V on U_{out}
Internal reference voltage @ I_{PN} = 0	$U_{I\,ref}$	V	1.63	1.65	1.67	
Nominal sensitivity	S_N	mV/A		62.5		500 mV @ I_{PN}
Temperature coefficient of S	TCS	ppm/K	−230		230	−40 °C ... 125 °C, including ratiometricity error
Electrical offset current referred to I_{PN}	I_{OE}	mA	−80		80	
Temperature coefficient of I_{OE}	TCI_{OE}	mA/K	−1.2		1.2	−40 °C ... 125 °C
Lifetime offset drift		mV		±2		
Noise voltage spectral density	u_{no}	$\dfrac{\mu V}{\sqrt{Hz}}$		8		100 Hz ... 100 kHz
Sensitivity error	ε_S	%	−1		1	
Ratiometricity error	ε_r	%		±0.5		
Ratiometricity offset error	ε_{rO}	mV	−10		10	U_C = 3.3 V ±10 %
Lifetime sensitivity error		% S		±1	±2	
Linearity error 0 ... I_{PN}	ε_L	% of I_{PN}	−0.3		0.3	Referred to I_{PN}
Linearity error 0 ... I_{PM}	ε_L	% of I_{PM}	−0.6		0.6	Referred to I_{PM}
Sum of sensitivity and linearity @ I_{PN}, @ T_A = 25 °C	ε_{SL25}	% of I_{PM}	−0.7		0.7	
Total error over temperature	ε_{tot}	% of I_{PM}	−1.2	0.5	1.2	

Electrical data GO 15-SME/SP4

At T_A = 25 °C, U_C = +3.3 V, R_L = 100 kΩ unless otherwise noted. Output mode: ratiometric.
(see Definition of typical, minimum and maximum values paragraph in page 12).

Parameter	Symbol	Unit	Min	Typ	Max	Conditions
Primary nominal RMS current	I_{PN}	A		15		800 mV on U_{out}
Primary current, measuring range	I_{PM}	A	−37.5		37.5	Full scale: 2 V on U_{out}
Internal reference voltage @ I_{PN} = 0	$U_{I\,ref}$	V	1.63	1.65	1.67	
Nominal sensitivity	S_N	mV/A		33.33		500 mV @ I_{PN}
Temperature coefficient of S	TCS	ppm/K	−230		230	−40 °C ... 125 °C, including ratiometricity error
Electrical offset current referred to I_{PN}	I_{OE}	mA	−125		125	
Temperature coefficient of I_{OE}	TCI_{OE}	mA/K	−1.88		1.88	−40 °C ... 125 °C
Lifetime offset drift		mV		±2		
Noise voltage spectral density	u_{no}	$\dfrac{\mu V}{\sqrt{Hz}}$		5		100 Hz ... 100 kHz
Sensitivity error	ε_S	%	−1		1	
Ratiometricity error	ε_r	%		±0.5		
Ratiometricity offset error	ε_{rO}	mV	−10		10	U_C = 3.3 V ±10 %
Lifetime sensitivity error		% S		±1	±2	
Linearity error 0 ... I_{PN}	ε_L	% of I_{PN}	−0.3		0.3	Referred to I_{PN}
Linearity error 0 ... I_{PM}	ε_L	% of I_{PM}	−0.6		0.6	Referred to I_{PM}
Sum of sensitivity and linearity @ I_{PN}, @ T_A = 25 °C	$\varepsilon_{SL\,25}$	% of I_{PM}	−0.7		0.7	
Total error over temperature	ε_{tot}	% of I_{PM}	−1.2	0.5	1.2	

Definition of typical, minimum and maximum values

Minimum and maximum values for specified limiting and safety conditions have to be understood as such as well as values shown in "typical" graphs.

On the other hand, measured values are part of a statistical distribution that can be specified by an interval with upper and lower limits and a probability for measured values to lie within this interval.

Unless otherwise stated (e.g. "100 % tested"), the LEM definition for such intervals designated with "min" and "max" is that the probability for values of samples to lie in this interval is 99.73 %.

For a normal (Gaussian) distribution, this corresponds to an interval between −3 sigma and +3 sigma. If "typical" values are not obviously mean or average values, those values are defined to delimit intervals with a probability of 68.27 %, corresponding to an interval between −sigma and +sigma for a normal distribution.

Typical, maximal and minimal values are determined during the initial characterization of the product.

Thermal characteristics

When designing a system containing a current transducer, self-heating due to the flow of the current should be considered.
When current passes through, the transducer's temperature will increase, and this may affect its performance.
This change of temperature will depend on the current profile, PCB layout, cooling techniques and copper thickness.
The following plots show an example of different thermal responses of the GO-SME transducer when used on an evaluation LEM board described on later paragraph.
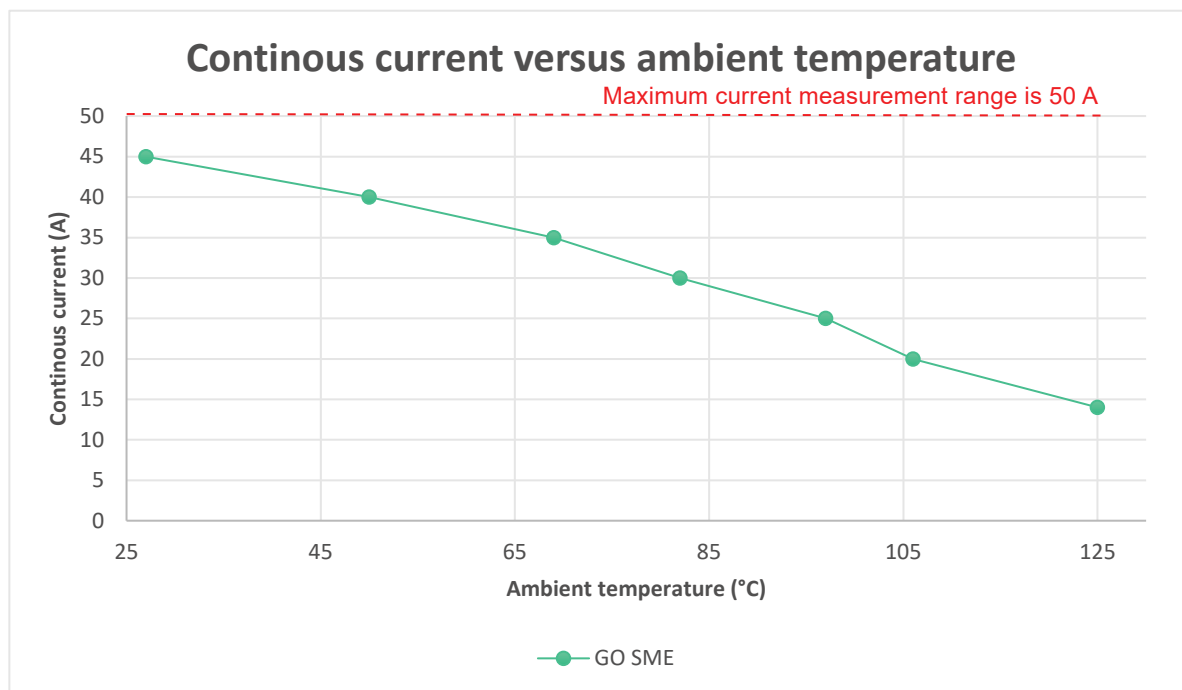
Figure 4: Continuous current vs temperature

The graph shows the mechanical capability of the GO-SME package.
The maximum current measurement range of the product is limited at 50 A.
The maximum temperature should be evaluated on the final system where the current transducer is integrated into the real application.
This temperature should never exceed the maximum junction temperature as shown on the previous paragraphs.

Sensitivity error
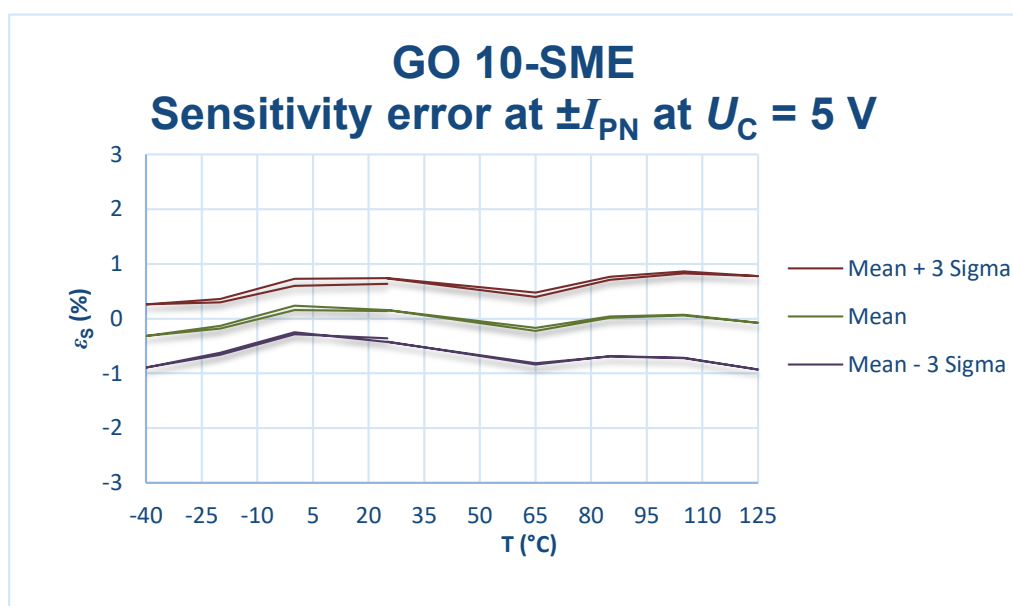
Figure 5: Sensitivity error (GO 10-SME)

Total error
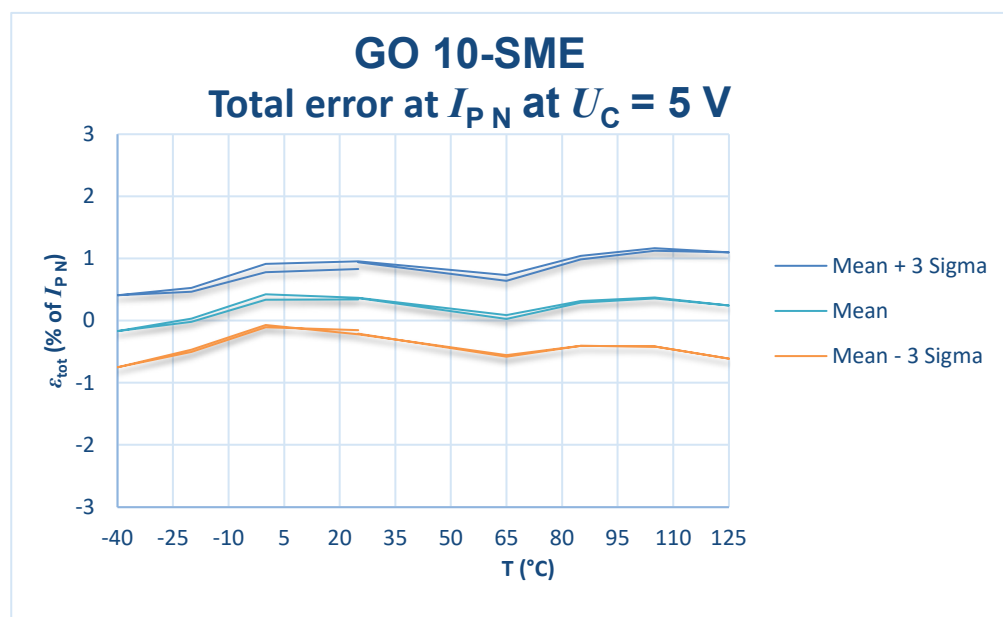
Figure 6: Total error over temperature

Delay time

Typical results measured on GO 10-SME @ I_{PN}

Ambient temperature (°C)	Delay time @ 10 %	Limit	Delay time @ 90 %	Limit
25	1.46	1.50	1.36	2.00
120	1.19	1.50	1.36	2.00
−40	1.42	1.50	1.35	2.00

Drifts over temperature (GO 10-SME)

Voltage offset drift over temperature
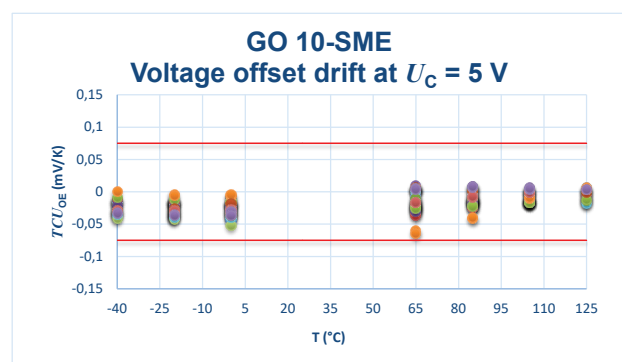
Sensitivity drift over temperature
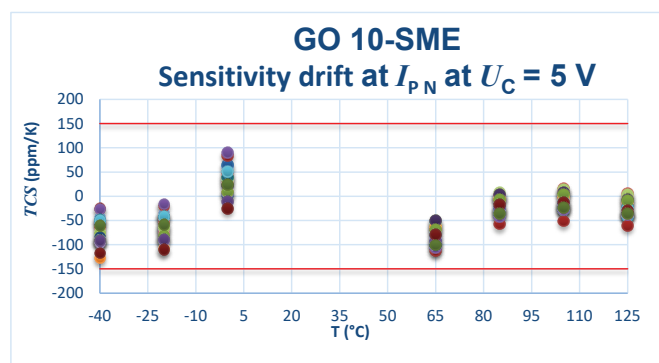
Figures 7, 8: Drifts over temperature

Evaluation board PCB 2320

All the above results are based on a LEM evaluation board.
This evaluation board is available at our distributors or direct sales (please contact us).

Description:

Evaluation board is based on 6 x 105 μm (3oz) copper layers.
6 x 500 sq. mm copper stitched on primary side.
This layout improves thermal performances of the transducer.
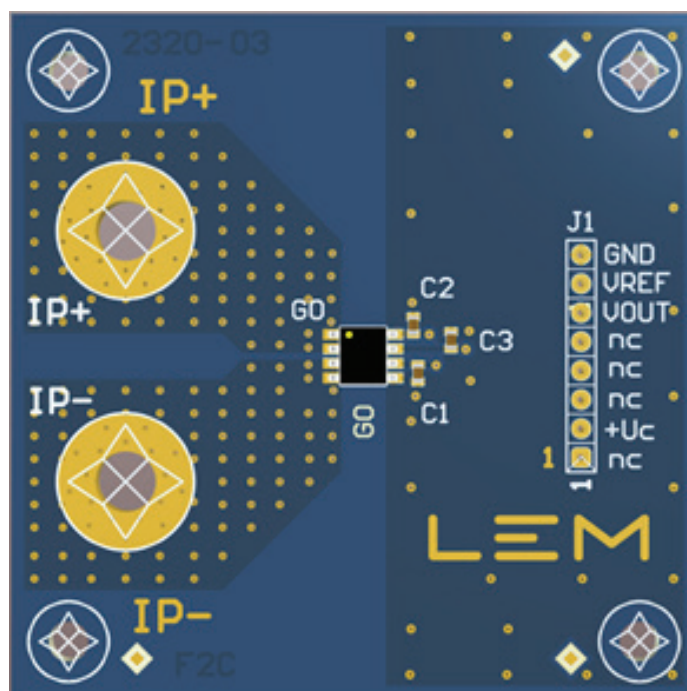
Figure 9: GO-SME Evaluation board
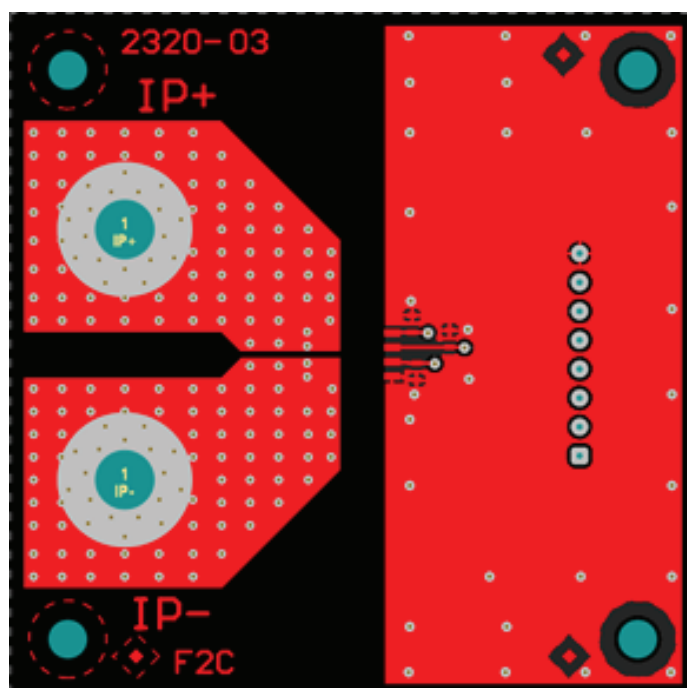
Figure 10: GO-SME Evaluation board layout

Contact LEM for more information about the evaluation board: https://www.lem.com/en/go-series

Terms and definitions

Total error referred to primary

The total error ε_{tot} is the error at $\pm I_{PN}$, relative to the rated value I_{PN}.
It includes all errors mentioned above
- the electrical offset I_{OE}
- the sensitivity error ε_S
- the linearity error ε_L (to I_{PN}).

$$\varepsilon_{tot} = \left(\frac{U_{out} - U_{out\,Th}}{S_N \times I_{PN}} \right) \times \left(\frac{100}{I_{PN}} \right)$$

Figure 11: Total error equation ε_{tot}

Electrical offset referred to primary

Using the current cycle shown in figure 14, the electrical offset current I_{OE} is the residual output referred to primary when the input current is zero.

$$I_{OE} = \frac{I_{P\,(3)} + I_{P\,(5)}}{2}$$

K_{OL}: Overload factor
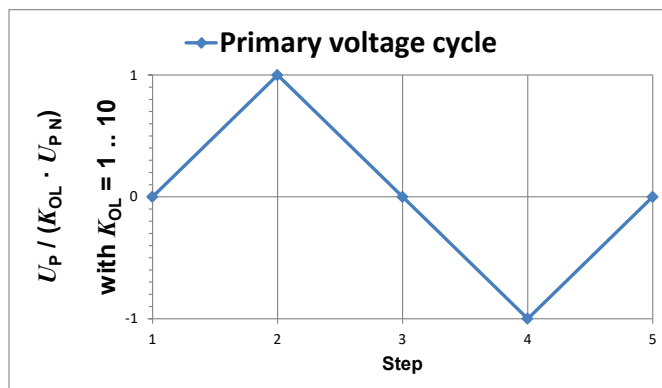
Figure 12: Current cycle used to measure electrical offset (transducer supplied)

Fixed and ratiometric modes

Ideally, $U_{out} - U_{ref} = 0$ V for $I_P = 0$ A

Fixed mode: U_{out} and U_{ref} are not scaled with the supply voltage. U_{ref} is trimmed during protection

Ratiometric mode: U_{out} and U_{ref} are scaled with the supply voltage.

Sensitivity and linearity

To measure sensitivity and linearity, the primary current (DC) is cycled from 0 to I_P, then to $-I_P$ and back to 0 (equally spaced $I_P/10$ steps). The sensitivity S is defined as the slope of the linear regression line for a cycle between $\pm I_{PN}$.
The linearity error ε_L is the maximum positive or negative difference between the measured points and the linear regression line, expressed in % of I_{PN}.

Delay times

The delay time $t_{D\,10}$ @ 10 % and the delay time $t_{D\,90}$ @ 90 % with respect to the primary are shown in the next figure.
Both slightly depend on the primary current di/dt.
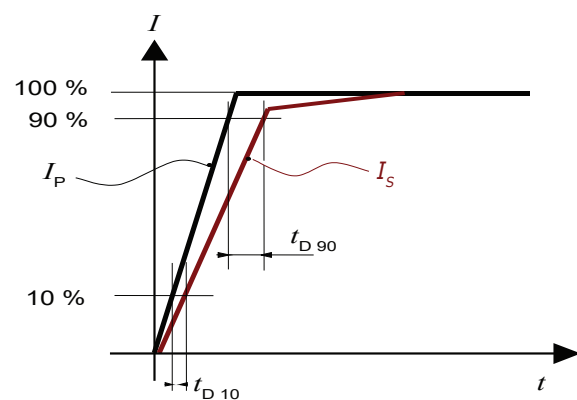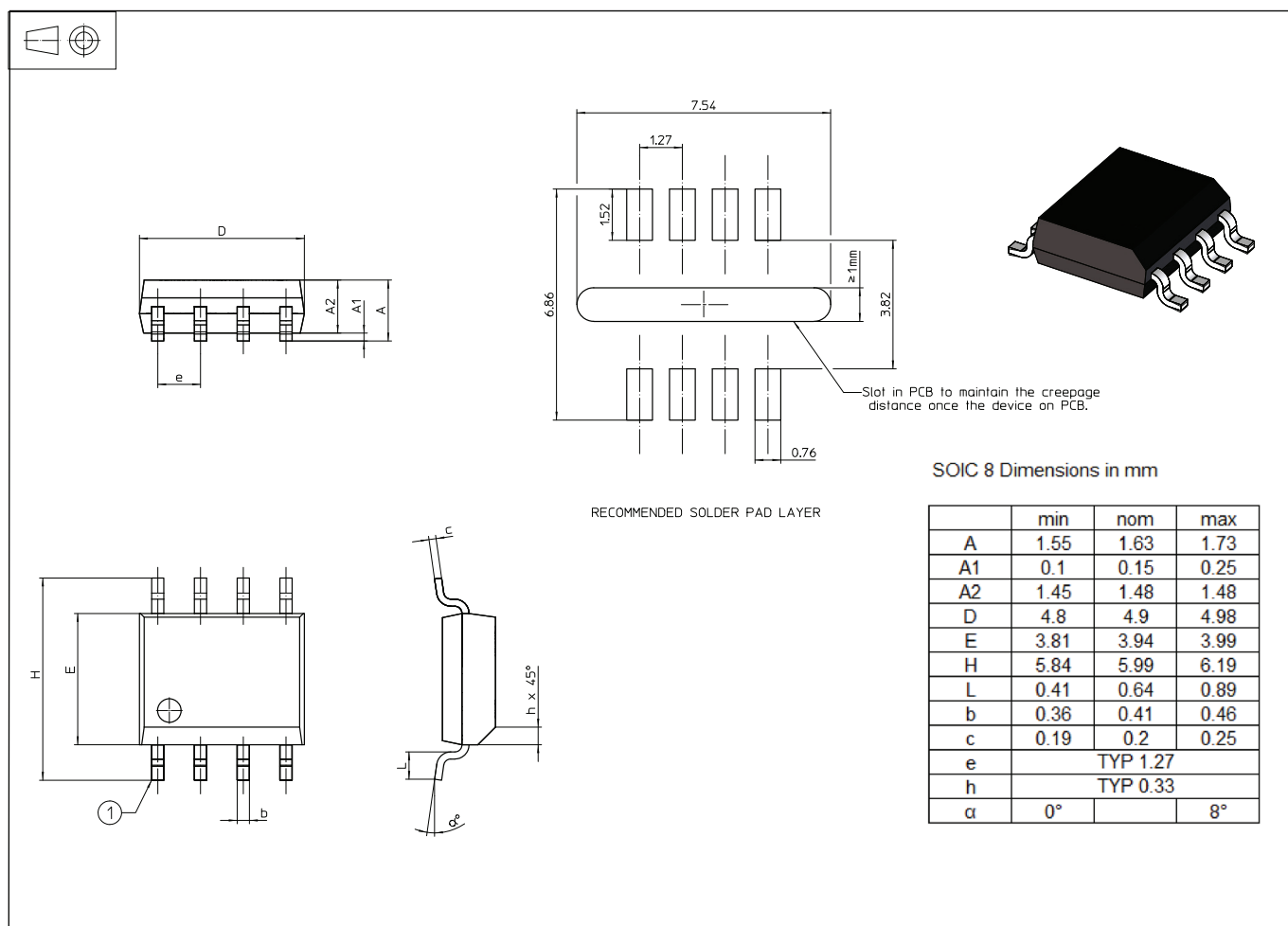They are measured at nominal current.

Figure 13: $t_{D\,10}$ (delay time @ 10 %) and $t_{D\,90}$ (delay time @ 90 %).

PCB footprint & dimensions (in mm)

RECOMMENDED SOLDER PAD LAYER

Slot in PCB to maintain the creepage distance once the device on PCB.

SOIC 8 Dimensions in mm

	min	nom	max
A	1.55	1.63	1.73
A1	0.1	0.15	0.25
A2	1.45	1.48	1.48
D	4.8	4.9	4.98
E	3.81	3.94	3.99
H	5.84	5.99	6.19
L	0.41	0.64	0.89
b	0.36	0.41	0.46
c	0.19	0.2	0.25
e	TYP 1.27		
h	TYP 0.33		
α	0°		8°

Mechanical characteristics: General tolerance ±0.15 mm

Remarks: $U_{out} - U_{ref}$ is positive when I_P flows in the direction of arrow (pin 1-2 to pin 3-4).

Soldering on PCB

Reflow soldering profile
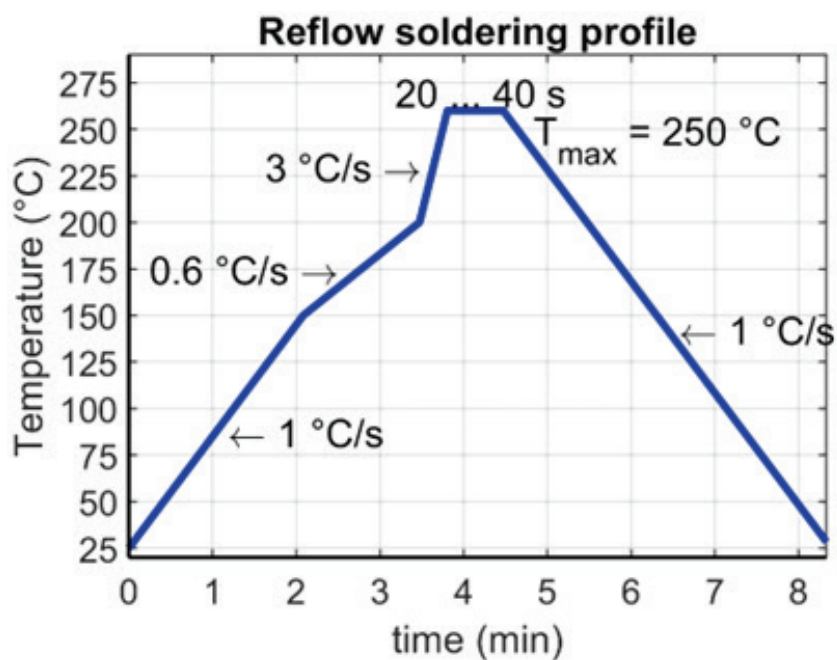
Soldering remarks:

- GO-SME is qualified MSL3 for storage and mounting purposes.
- Per JEDEC J-STD-020 for packages less than 2.5 mm thick per table 4.2 (Pb-Free process) of the specification.
- Best practice is to use 7 zones or greater conventional reflow system, limiting the time at reflow temperature as indicated in profile above.
- Rework not recommended.
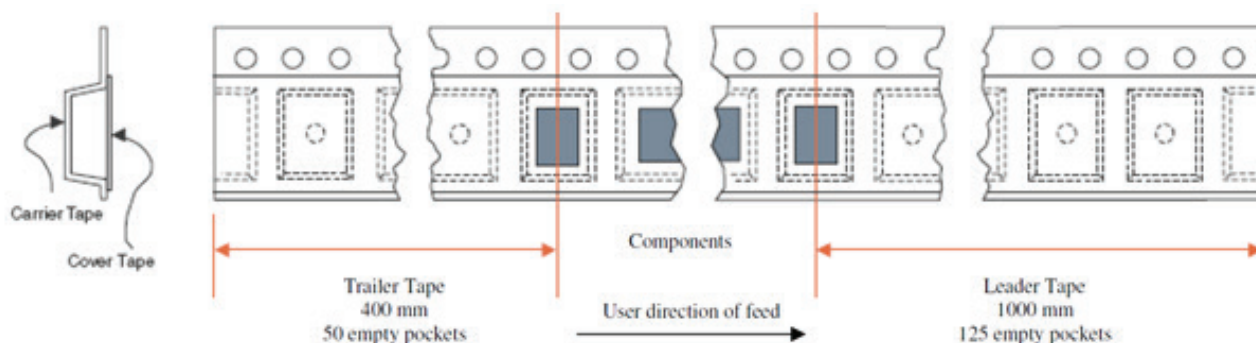
Tape and reel dimensions (in mm)

Leader & Trailer:

Figure 14: Leader and trailer

Carrier Tape Data:
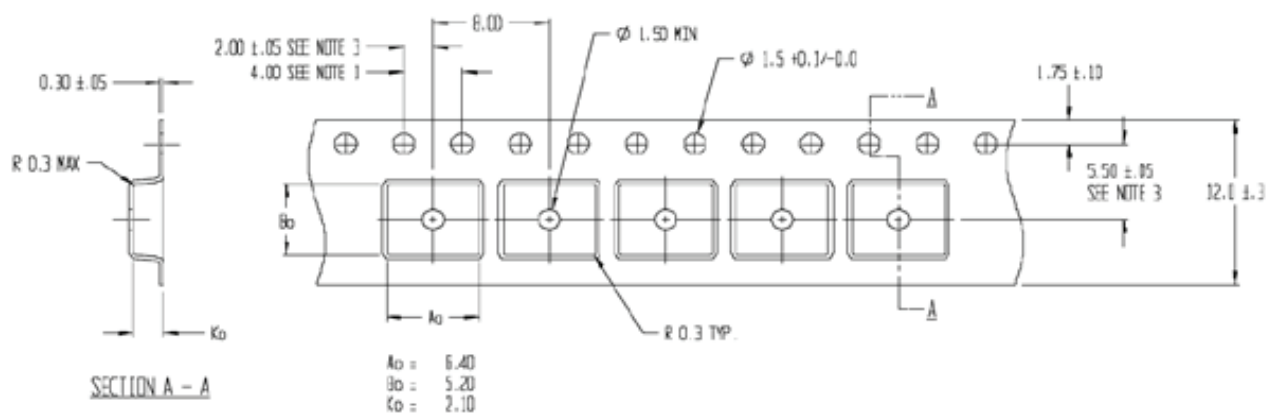
Figure 14: Carrier tape
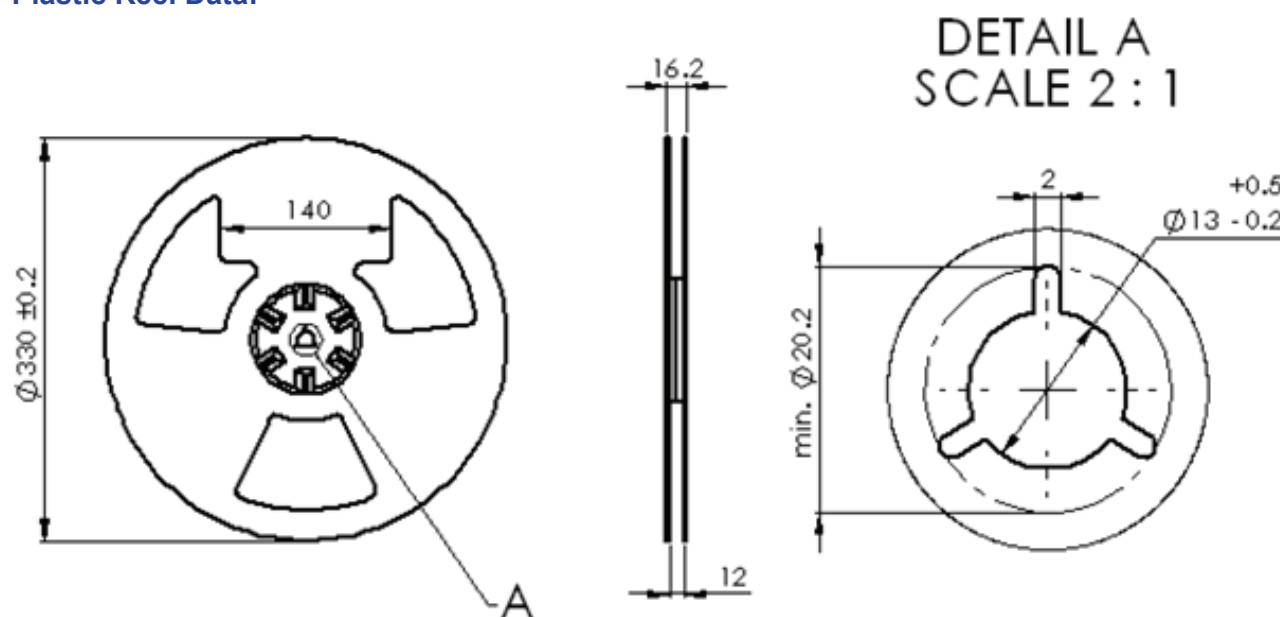
Plastic Reel Data:

Figure 15: Plastic reel

Safety

⚠️
Caution

This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions..

⚠️
Caution, risk of electrical shock

This transducer must be used in limited-energy secondary circuits according to IEC 62368-1.
When operating the transducer, certain parts of the module can carry hazardous voltages and high currents (e.g. power supply, primary conductor).
Ignoring this warning can lead to injury and or/cause serious damage.
This transducer is a build-in device, whose hazardous live parts must be inaccessible after installation.
A protective enclosure or additional shield could be used. Main supply must be able to be disconnected.

Therefore, LEM cannot be held liable for any potential hazards, damages, injuries or loss of life resulting from the use of this product.

ESD susceptibility

This product is susceptible to be damaged from an ESD event and the personnel and workspace should be grounded when handling it.

c**Ru**®us

Underwriters Laboratory Inc. recognized component

Version history

Date	Version	Comments
17 November 2021	0	New generic datasheet with SP products
22 June 2022	1	Modified definition paragraph + modified 3D picture (page 1); replaced ms by µs (page 7) + modified LEM address + last sentence (all pages)
29 November 2022	2	Modified Nominal sensitivity is 50 instead of 62.5 (page 11)
2 May 2023	3	Modified "Main features & advantages" paragraph (page 1) + modfied "Application circuit and pinout" connection + modified text in "Function" column on first table + added "Note" paragraph (page 2) + modified text in line under the standards products table (page 3) + modified "Note" sentence (page 4) + added red text and line on curve (page 13) + deleted magnetic current paragraph (page 17)

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GO 10-SME Demo Board GO 20-SME Demo Board GO 10-SME/SP3 Demo Board GO 20-SME/SP3 GO 20-SME GO 20-SME/SP3 Demo Board GO 10-SME GO 10-SME/SP3 GO 10-SME SET OF 50 PCS GO 20-SME/SP2 GO 20-SME SET OF 50 PCS GO 20-SME/SP2 SET OF 50 GO 20-SME/SP3 SET OF 50 GO 10-SME/SP3 SET OF 50 GO 20-SME KIT 5P GO 20-SME/SP2 KIT 5P GO 12-SME/SP2 SET OF 50 GO 15-SME/SP4 SET OF 50 GO 12-SME/SP2 KIT 5P GO 8-SME/SP4 SET OF 50 GO 8-SME/SP4 GO 15-SME/SP4 KIT 5P GO 12-SME/SP2 GO 20-SME/SP3 KIT 5P GO 10-SME KIT 5P GO 15-SME/SP4 GO 10-SME/SP3 KIT 5P